



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

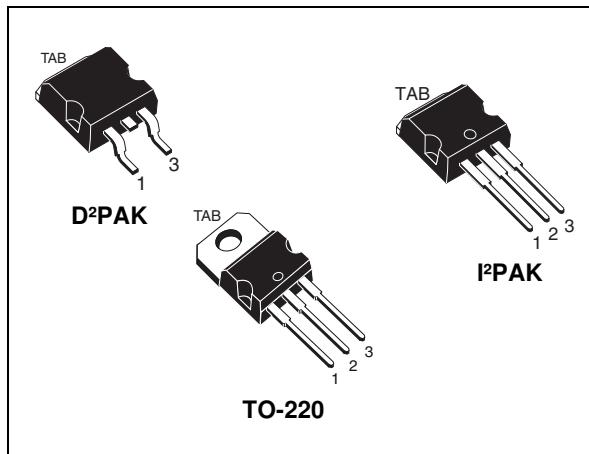


## Contact us

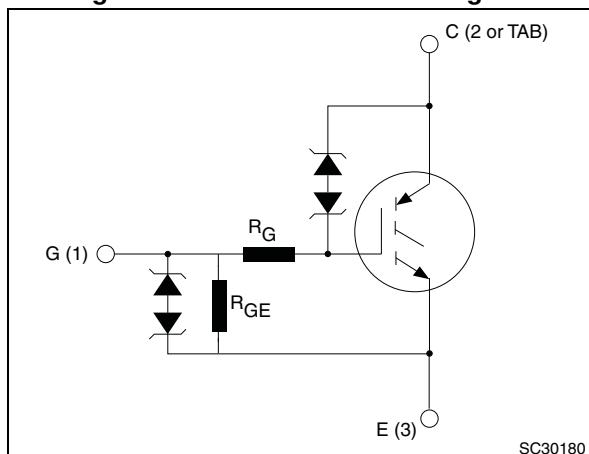
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



**Figure 1. Internal schematic diagram**



## Features

- Designed for automotive applications and AEC-Q101 qualified
- Low threshold voltage
- Low on-voltage drop
- High voltage clamping feature
- Logic level gate charge
- ESD gate-emitter protection
- Gate and gate-emitter integrated resistors

## Application

- Automotive ignition

## Description

This application specific IGBT utilizes the most advanced PowerMESH™ technology. The built-in Zener diodes between gate-collector and gate-emitter provide overvoltage protection capabilities. The device also exhibits low on-state voltage drop and low threshold drive for use in automotive ignition system.

**Table 1. Device summary**

Order codes	Marking	Package	Packaging
STGB35N35LZ-1	GB35N35LZ	I²PAK	Tube
STGB35N35LZT4	GB35N35LZ	D²PAK	Tape and reel
STGP35N35LZ	GP35N35LZ	TO-220	Tube

## Contents

<b>1</b>	<b>Electrical ratings</b>	<b>3</b>
<b>2</b>	<b>Electrical characteristics</b>	<b>4</b>
2.1	Electrical characteristics (curves)	6
<b>3</b>	<b>Test circuits</b>	<b>9</b>
<b>4</b>	<b>Package mechanical data</b>	<b>10</b>
<b>5</b>	<b>Packaging mechanical data</b>	<b>15</b>
<b>6</b>	<b>Revision history</b>	<b>17</b>

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-emitter voltage ( $V_{GE} = 0$ )	$V_{CES}$ (clamped)	V
$V_{ECS}$	Emitter collector voltage ( $V_{GE} = 0$ )	20	V
$I_C^{(1)}$	Continuous collector current at $T_C = 25^\circ\text{C}$	40	A
$I_C^{(1)}$	Continuous collector current at $T_C = 100^\circ\text{C}$	30	A
$I_{CP}^{(2)}$	Pulsed collector current	80	A
$V_{GE}$	Gate-emitter voltage	$V_{GE}$ (clamped)	V
$P_{TOT}$	Total dissipation at $T_C = 25^\circ\text{C}$	176	W
$E_{AS}$	Single pulse energy ( $T_C=25^\circ\text{C}$ , $L=1.6\text{ mH}$ , $I_C = 22\text{ A}$ , $V_{CC} = 50\text{ V}$ )	450	mJ
ESD	Human body model ( $R=1,5\text{ k}\Omega$ , $C=100\text{ pF}$ )	8	kV
	Machine model ( $R=0$ , $C=100\text{ pF}$ )	800	V
	Charged device model	2	kV
$T_{stg}$	Storage temperature	– 55 to 175	$^\circ\text{C}$
$T_j$	Operating junction temperature		

1. Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{j(\max)} - T_C}{R_{thj-c} \times V_{CE(sat)(\max)}(T_{j(\max)}, I_C(T_C))}$$

2. Pulse width limited by maximum junction temperature

**Table 3. Thermal data**

Symbol	Parameter	Value	Unit
$R_{thj-case}$	Thermal resistance junction-case	0.85	$^\circ\text{C/W}$
$R_{thj-amb}$	Thermal resistance junction-ambient	62.5	$^\circ\text{C/W}$

## 2 Electrical characteristics

( $T_j = 25^\circ\text{C}$  unless otherwise specified)

**Table 4. Static**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{CES(\text{clamped})}$	Collector emitter clamped voltage ( $V_{GE}=0$ )	$I_C=2 \text{ mA},$		345		V
		$I_C=2 \text{ mA}, T_j = -40^\circ\text{C} \text{ to } 150^\circ\text{C}$	320		380	V
$V_{(BR)ECS}$	Emitter collector breakdown voltage ( $V_{GE}=0$ )	$I_C = 75 \text{ mA}$	20	28		V
$V_{GE(\text{clamped})}$	Gate emitter clamped voltage	$I_G = \pm 2 \text{ mA}$	12	14	16	V
$I_{CES}$	Collector cut-off current ( $V_{GE} = 0$ )	$V_{CE} = 15 \text{ V}, T_j = 150^\circ\text{C}$			10	$\mu\text{A}$
		$V_{CE} = 200 \text{ V}, T_j = 150^\circ\text{C}$			100	$\mu\text{A}$
$I_{GES}$	Gate-emitter leakage current ( $V_{CE} = 0$ )	$V_{GE} = \pm 10 \text{ V}$	500	625	830	$\mu\text{A}$
$R_{GE}$	Gate emitter resistance		12	15	20	$\text{k}\Omega$
$R_G$	Gate resistance			1.5		$\text{k}\Omega$
$V_{GE(\text{th})}$	Gate threshold voltage	$V_{CE} = V_{GE}, I_C = 1 \text{ mA}, T_j = -40^\circ\text{C}$	1.4			V
		$V_{CE} = V_{GE}, I_C = 1 \text{ mA}$	1.2	1.6	2.3	V
		$V_{CE} = V_{GE}, I_C = 1 \text{ mA}, T_j = 150^\circ\text{C}$	0.7			V
$V_{CE(\text{sat})}$	Collector-emitter saturation voltage	$V_{GE} = 4.5 \text{ V}, I_C = 10 \text{ A}$		1.15	1.5	V
		$V_{GE} = 4.5 \text{ V}, I_C = 15 \text{ A}$		1.3	1.7	V

**Table 5. Dynamic**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$C_{ies}$	Input capacitance	$V_{CE} = 25 \text{ V}, f = 1 \text{ MHz}, V_{GE} = 0$	-	700	-	pF
$C_{oes}$	Output capacitance		-	150	-	pF
$C_{res}$	Reverse transfer capacitance		-	6	-	pF
$Q_g$	Gate charge	$V_{CE} = 280 \text{ V}, I_C = 15 \text{ A}, V_{GE} = 5 \text{ V}$	-	49	-	nC

**Table 6. Functional characteristics**

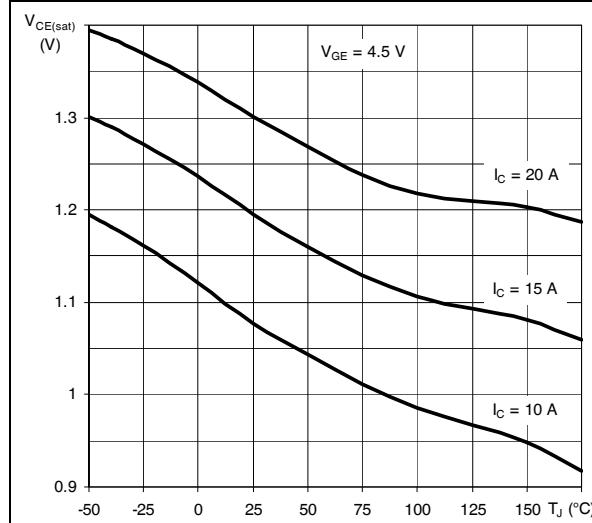
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
U.I.S.	Functional test open secondary coil	$R_G = 0$ , $T_j = 150^\circ\text{C}$ , $V_{CC} = 50\text{ V}$ , $V_{GE} = 5\text{ V}$ , $L=1.6\text{ mH}$	18	-	-	A

**Table 7. Switching time**

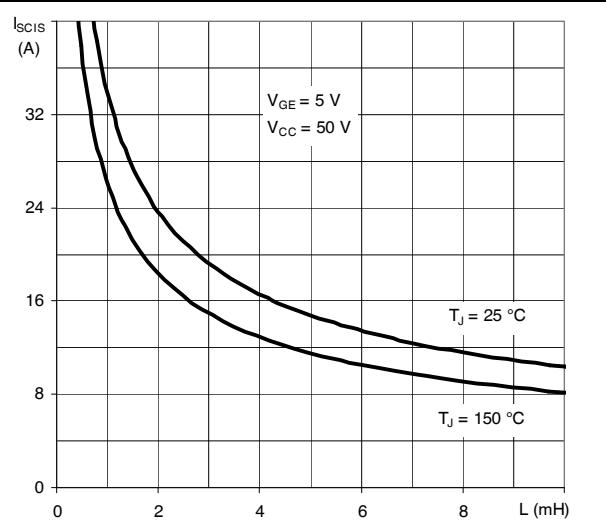
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ $t_r$	Resistive load Turn-on delay time Rise time	$V_{CC} = 14\text{ V}$ , $R_L = 1\Omega$ , $V_{GE} = 5\text{ V}$	-	1.1 7	-	$\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
$t_{d(on)}$ $t_r$	Resistive load Turn-on delay time Rise time	$V_{CC} = 14\text{ V}$ , $R_L = 1\Omega$ , $V_{GE} = 5\text{ V}$ $T_j = 150^\circ\text{C}$	-	1 6.6	-	$\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
$t_{d(off)}$ $t_f$ $dv/dt$	Inductive load Turn-off delay time Fall time Turn-off voltage slope	$V_{CC} = 300\text{ V}$ , $L = 1\text{ mH}$ $I_C = 15\text{ A}$ , $V_{GE} = 5\text{ V}$	-	26.5 5.5 70	-	$\mu\text{s}$ $\mu\text{s}$ $\text{V}/\mu\text{s}$
$t_{d(off)}$ $t_f$ $dv/dt$	Inductive load Turn-off delay time Fall time Turn-off voltage slope	$V_{CC} = 300\text{ V}$ , $L = 1\text{ mH}$ $I_C = 15\text{ A}$ , $V_{GE} = 5\text{ V}$ $T_j = 150^\circ\text{C}$	-	28 9 65	-	$\mu\text{s}$ $\mu\text{s}$ $\text{V}/\mu\text{s}$

## 2.1 Electrical characteristics (curves)

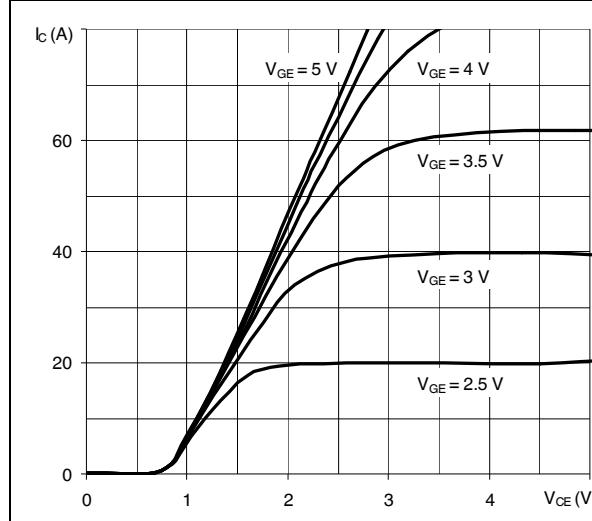
**Figure 2. Collector-emitter saturation voltage vs temperature**



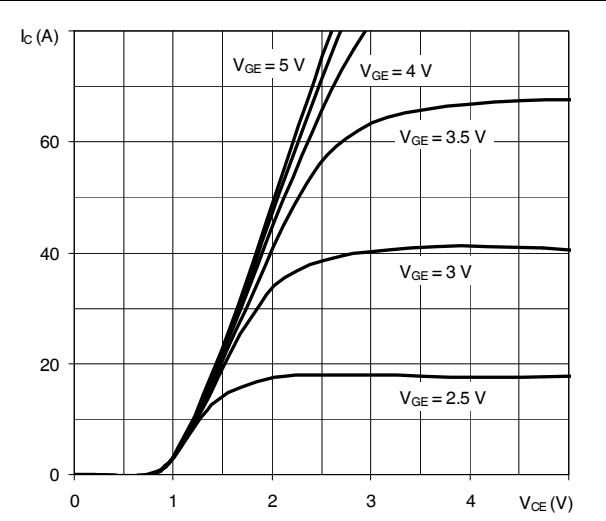
**Figure 3. Self clamped inductive switch**

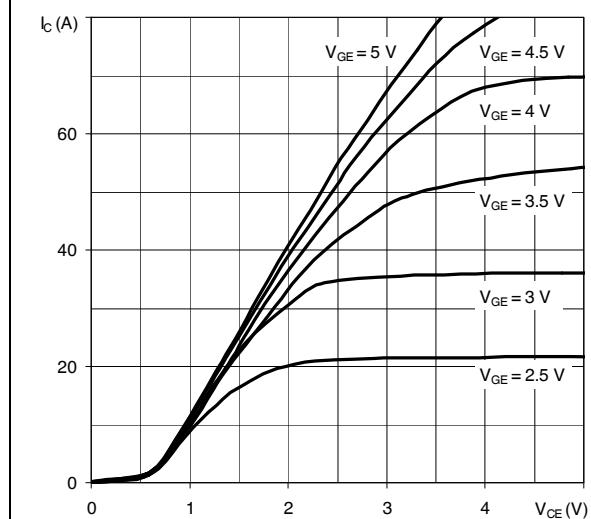
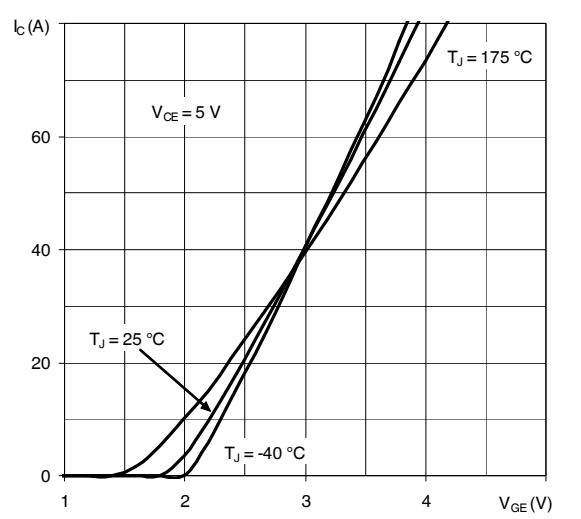
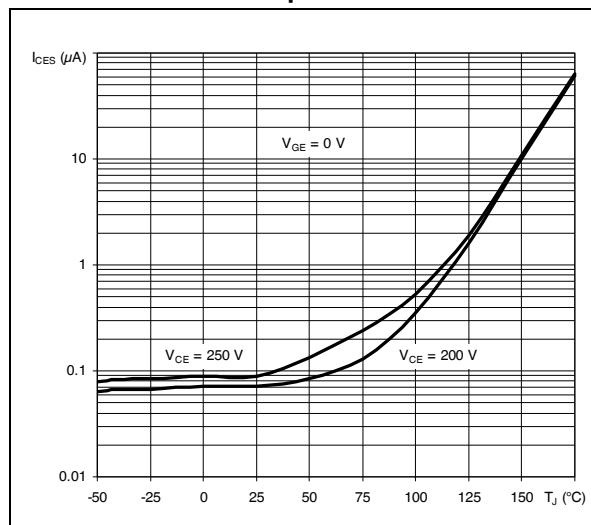
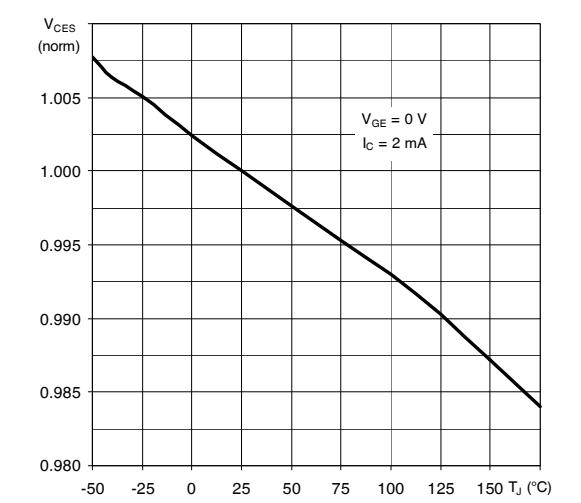


**Figure 4. Output characteristics ( $T_J = 25^\circ\text{C}$ )**

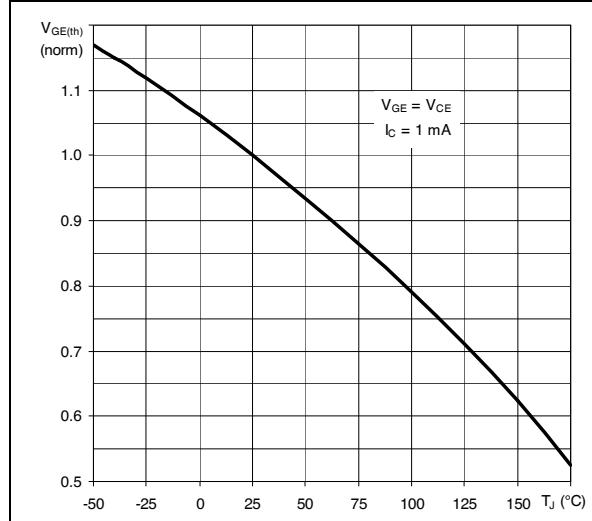


**Figure 5. Output characteristics ( $T_J = -40^\circ\text{C}$ )**

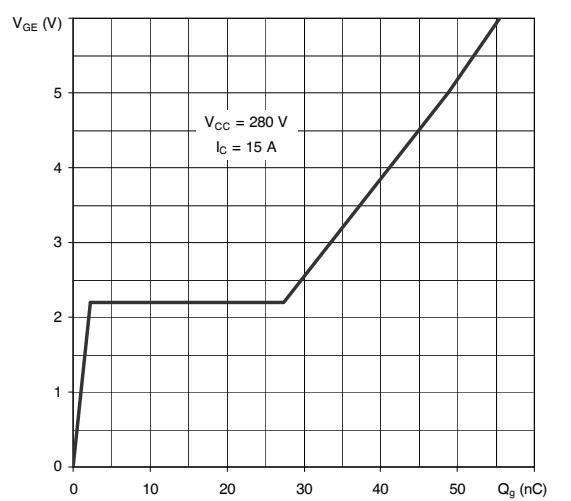


**Figure 6. Output characteristics ( $T_J = 175^\circ\text{C}$ )****Figure 7. Transfer characteristics****Figure 8. Collector cut-off current vs temperature****Figure 9. Normalized collector emitter voltage vs temperature**

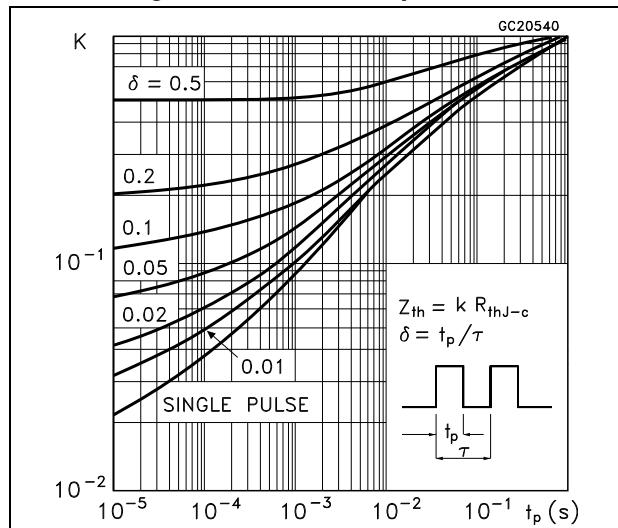
**Figure 10. Normalized gate threshold voltage vs temperature**



**Figure 11. Gate charge**

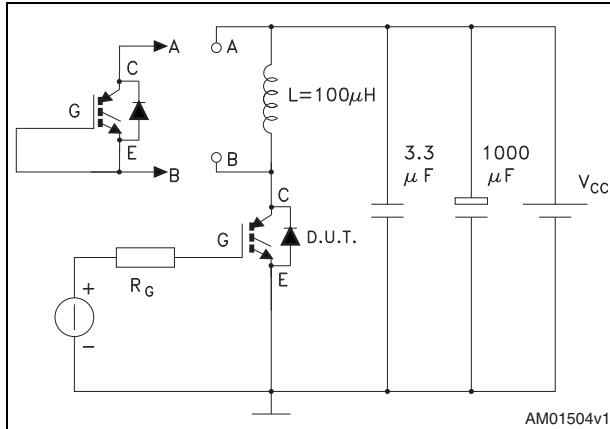


**Figure 12. Thermal impedance**

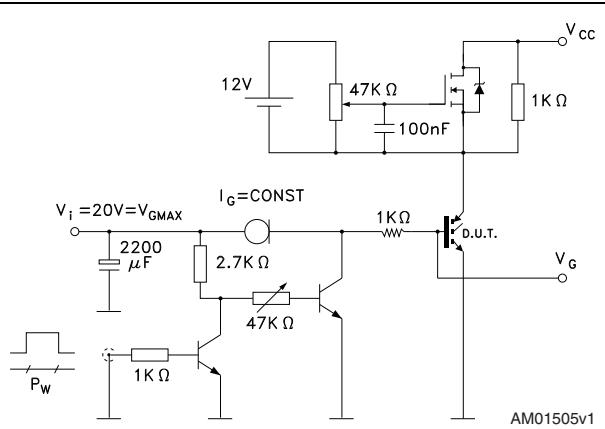


### 3 Test circuits

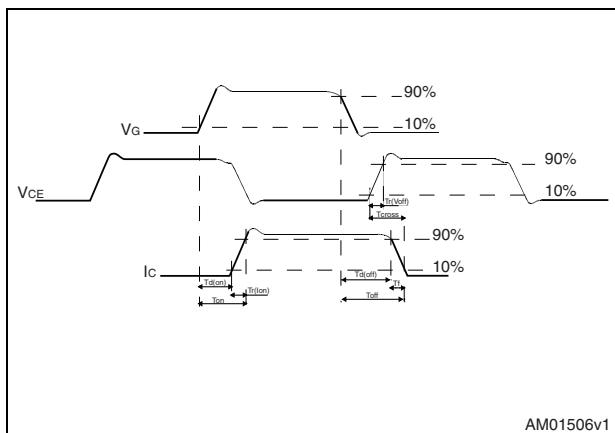
**Figure 13. Test circuit for inductive load switching**



**Figure 14. Gate charge test circuit**



**Figure 15. Switching waveform**

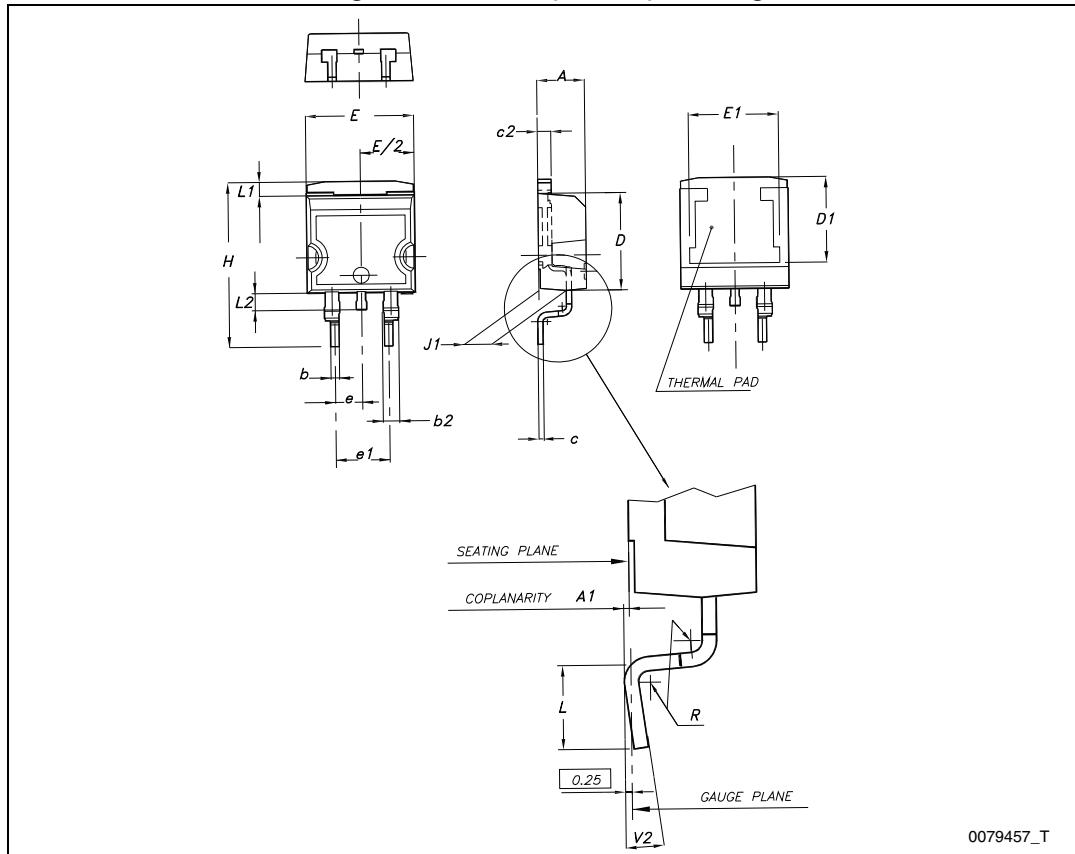
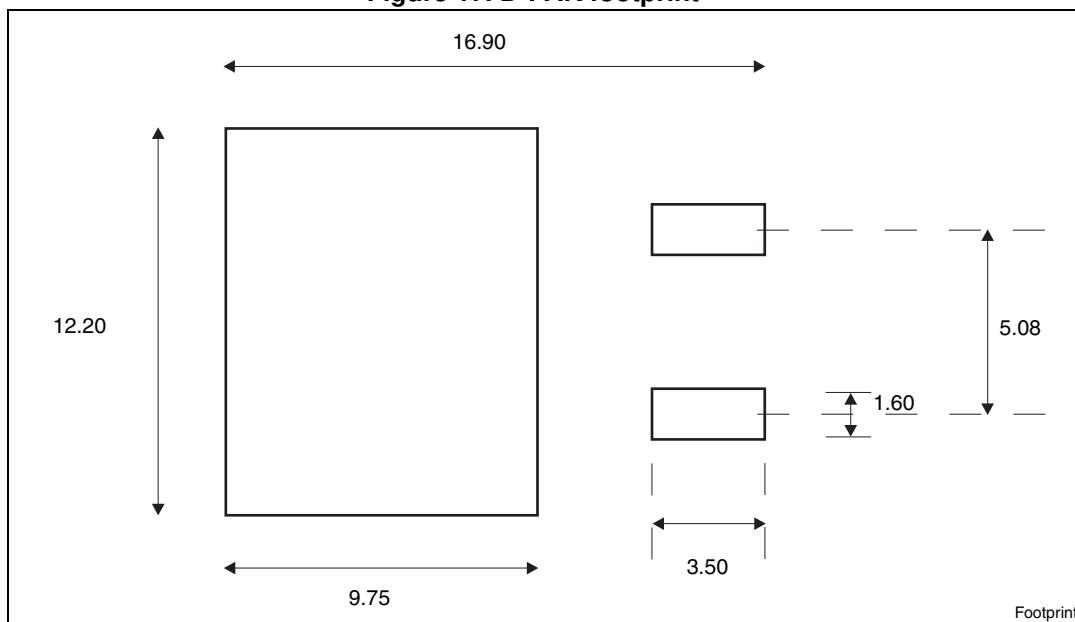


## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
ECOPACK is an ST trademark.

**Table 8. D<sup>2</sup>PAK (TO-263) mechanical data**

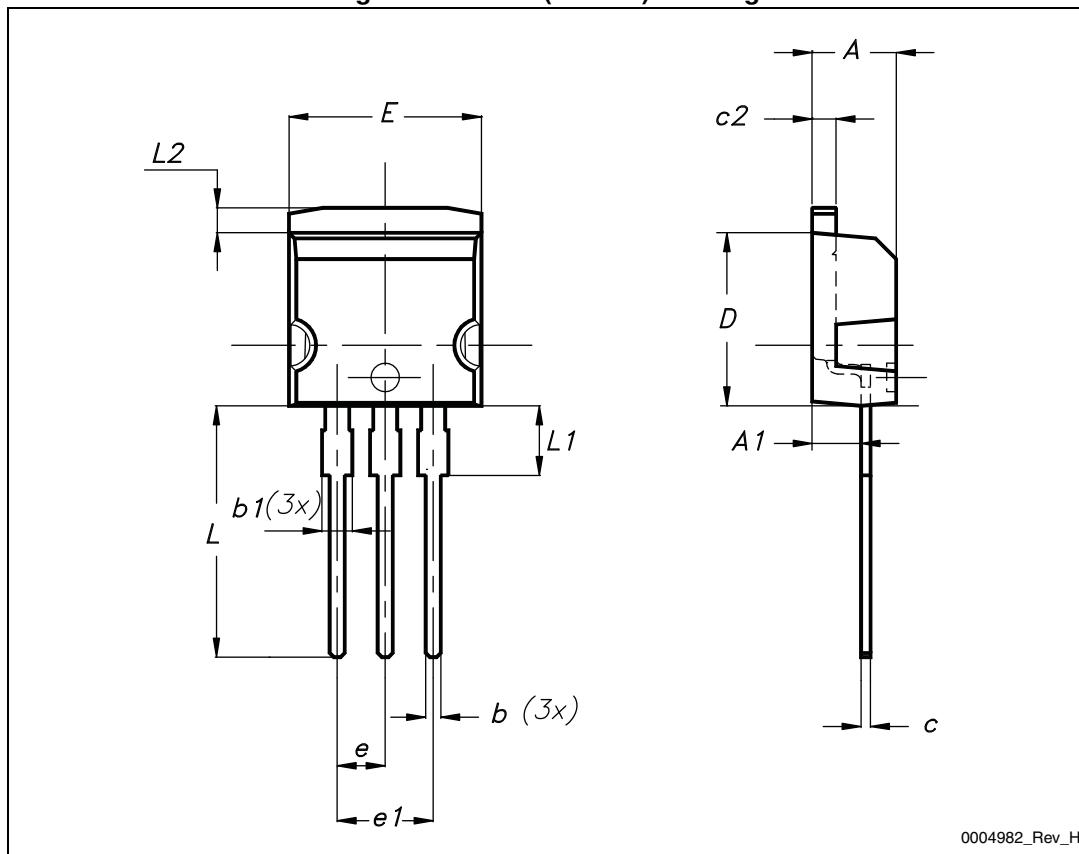
Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
A1	0.03		0.23
b	0.70		0.93
b2	1.14		1.70
c	0.45		0.60
c2	1.23		1.36
D	8.95		9.35
D1	7.50		
E	10		10.40
E1	8.50		
e		2.54	
e1	4.88		5.28
H	15		15.85
J1	2.49		2.69
L	2.29		2.79
L1	1.27		1.40
L2	1.30		1.75
R		0.4	
V2	0°		8°

**Figure 16. D<sup>2</sup>PAK (TO-263) drawing****Figure 17. D<sup>2</sup>PAK footprint<sup>(a)</sup>**

a. All dimension are in millimeters

Table 9. I<sup>2</sup>PAK (TO-262) mechanical data

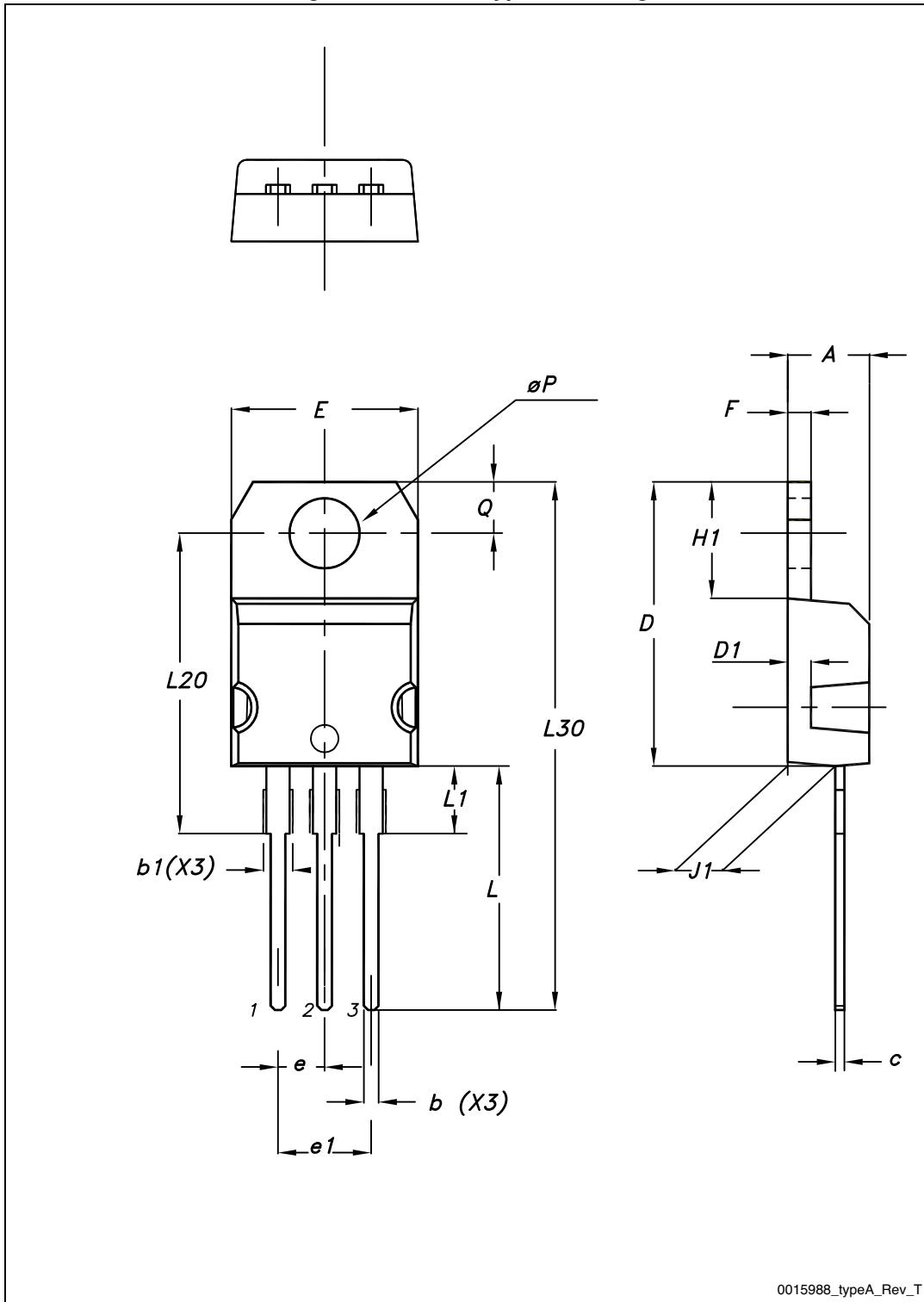
DIM.	mm.		
	min.	typ	max.
A	4.40		4.60
A1	2.40		2.72
b	0.61		0.88
b1	1.14		1.70
c	0.49		0.70
c2	1.23		1.32
D	8.95		9.35
e	2.40		2.70
e1	4.95		5.15
E	10		10.40
L	13		14
L1	3.50		3.93
L2	1.27		1.40

Figure 18. I<sup>2</sup>PAK (TO-262) drawing

**Table 10. TO-220 type A mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

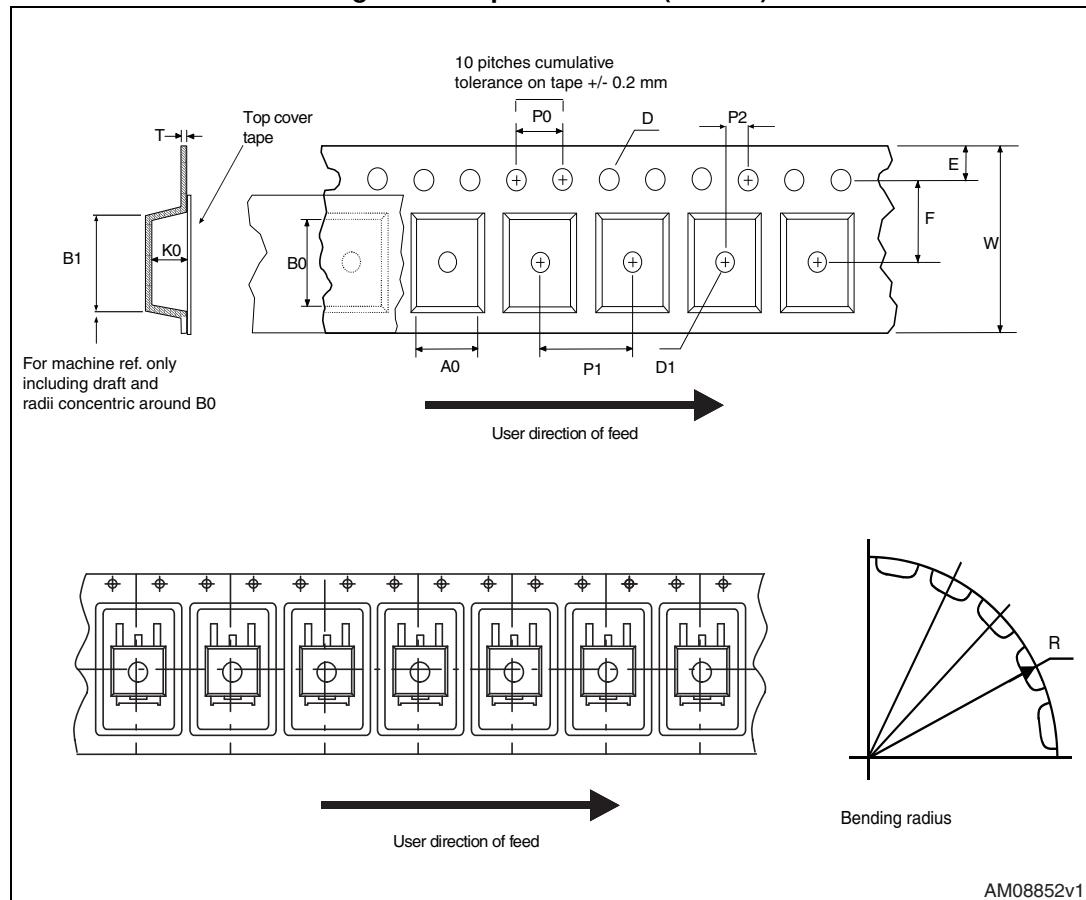
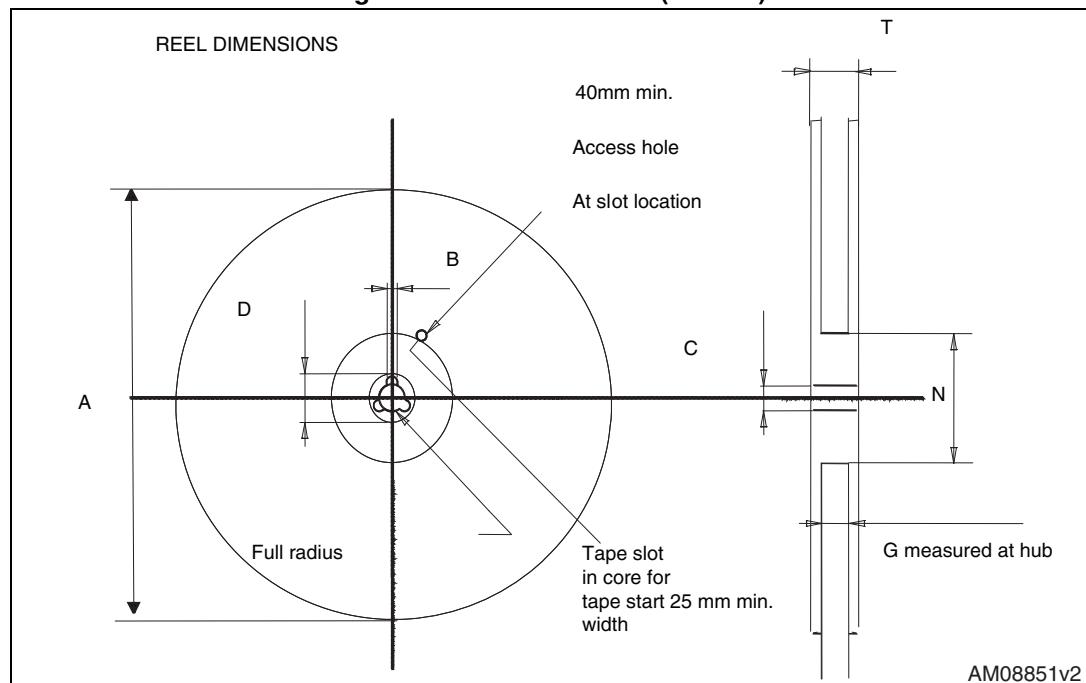
Figure 19. TO-220 type A drawing



## 5 Packaging mechanical data

Table 11. D<sup>2</sup>PAK (TO-263) tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1		Base qty	1000
P2	1.9	2.1		Bulk qty	1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

Figure 20. Tape for D<sup>2</sup>PAK (TO-263)Figure 21. Reel for D<sup>2</sup>PAK (TO-263)

## 6 Revision history

Table 12. Document revision history

Date	Revision	Changes
29-Mar-2006	1	Initial release.
03-Jun-2009	2	Document status promoted from preliminary data to datasheet.
05-Nov-2009	3	Inserted <i>Chapter 2.1: Electrical characteristics (curves)</i>
16-Feb-2010	4	Added new package, mechanical data: TO-220
03-Jun-2010	5	<ul style="list-style-type: none"><li>– Added <i>Figure 12: Thermal impedance</i></li><li>– Modified <i>Figure 4</i>, <i>Figure 5</i>, <i>Figure 6</i> and <i>Figure 7</i></li><li>– D<sup>2</sup>PAK mechanical data has been updated</li></ul>
28-May-2013	6	<ul style="list-style-type: none"><li>– Updated title in cover page, <i>Chapter 5: Packaging mechanical data</i> and <i>Chapter 5: Packaging mechanical data</i>.</li></ul>

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**ST PRODUCTS ARE NOT AUTHORIZED FOR USE IN WEAPONS. NOR ARE ST PRODUCTS DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)